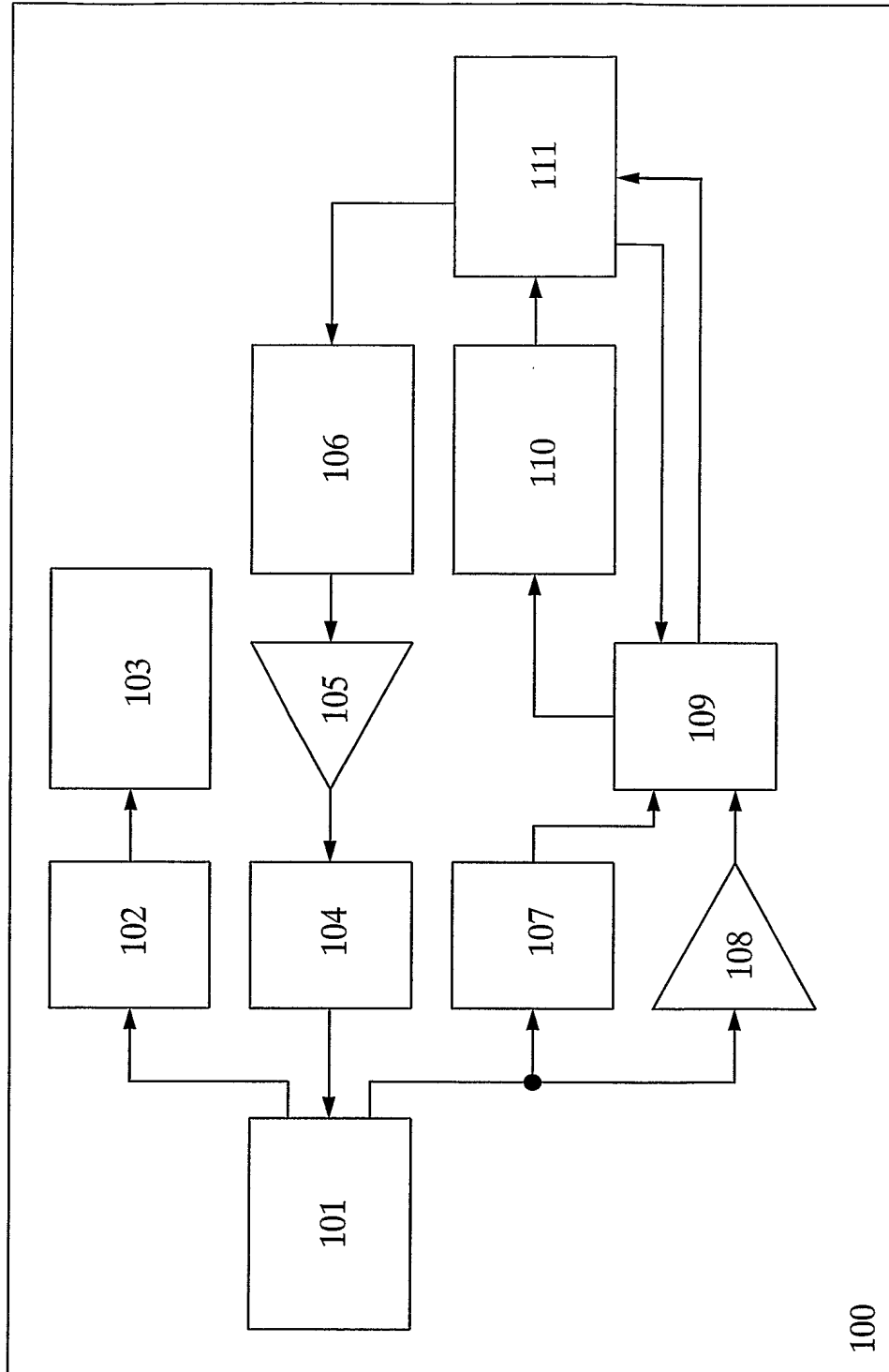


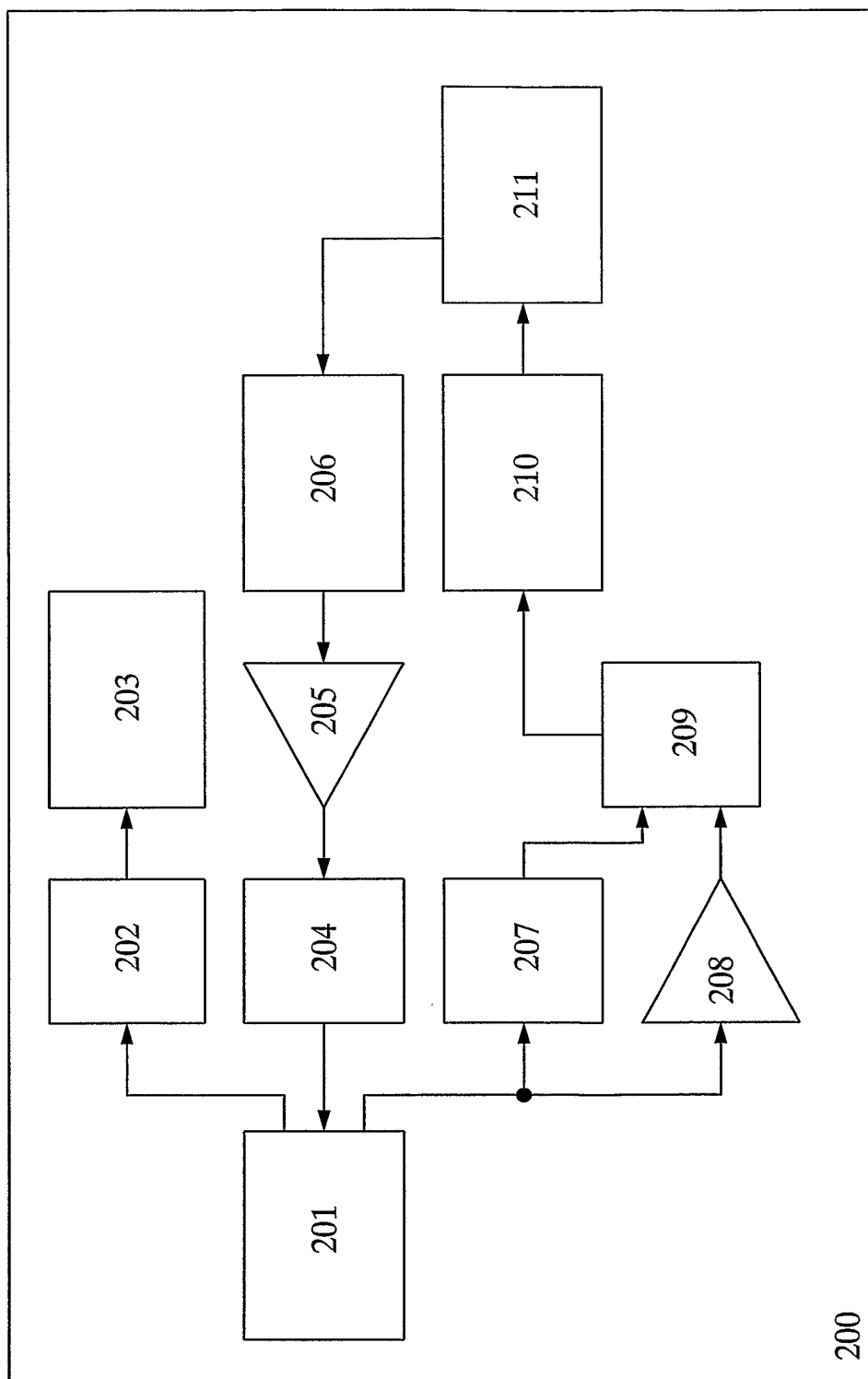
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FIG. 1



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FIG. 2



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FIG. 3A

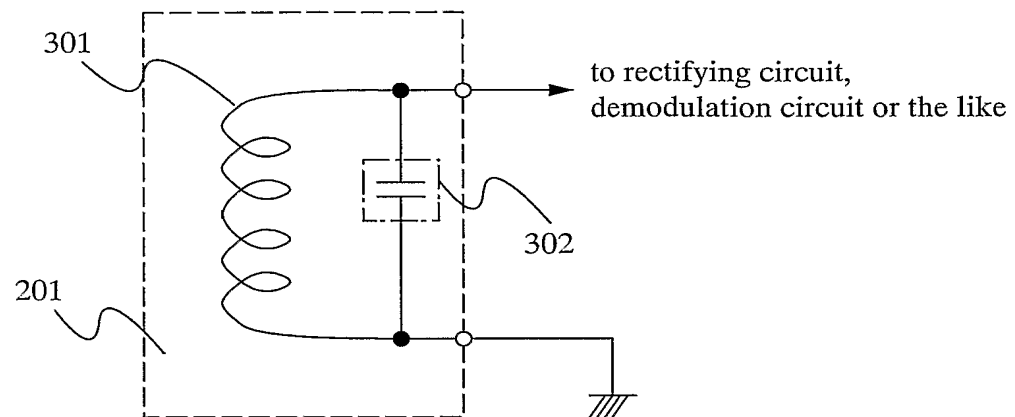
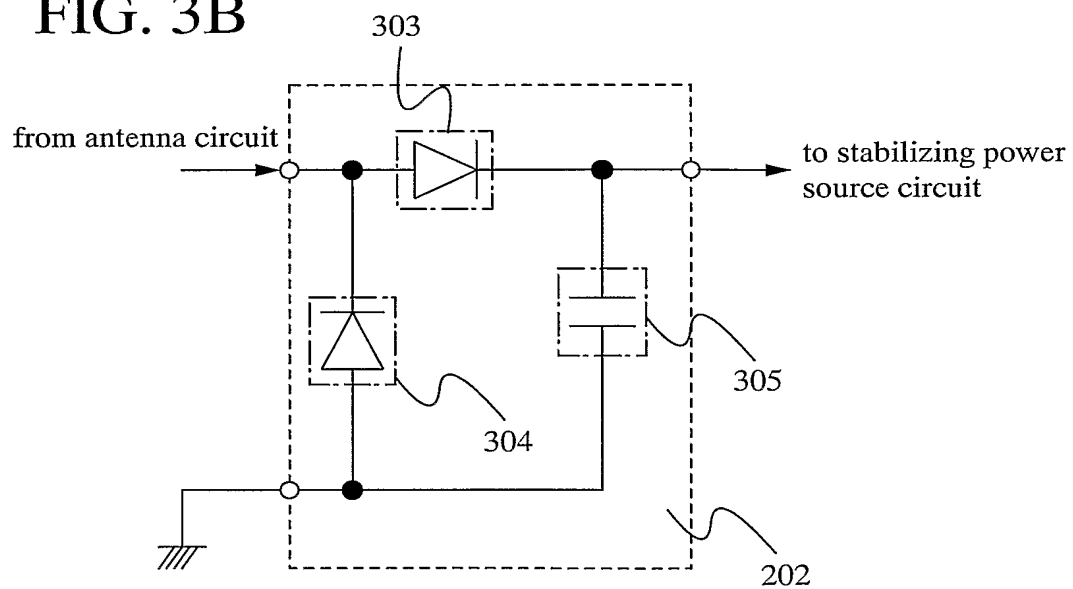
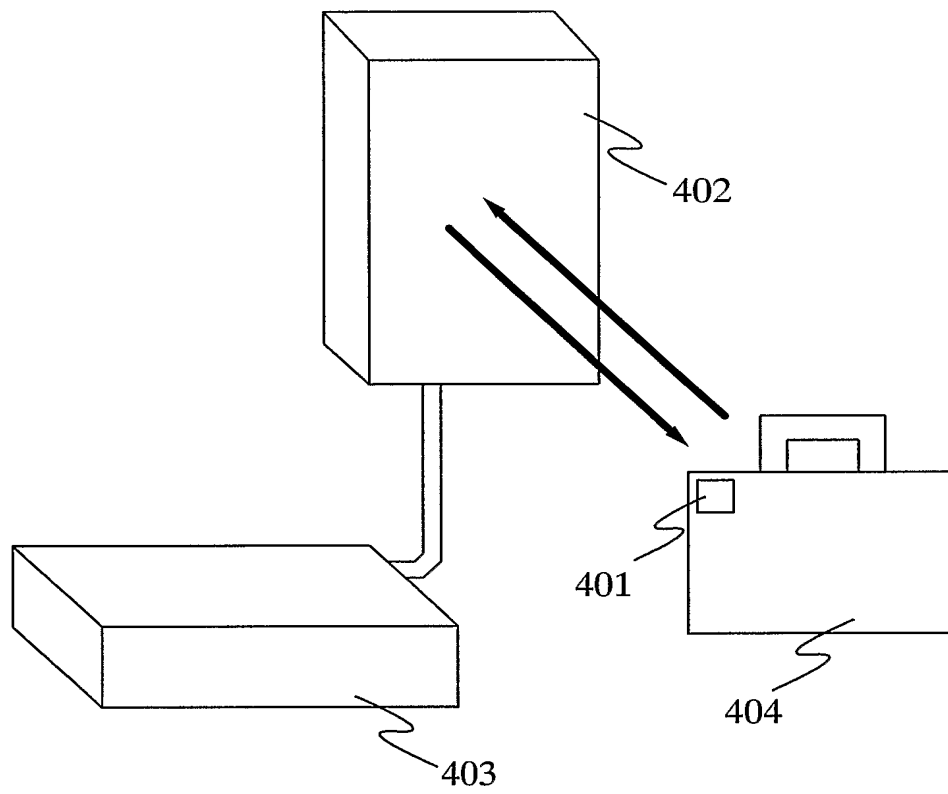


FIG. 3B



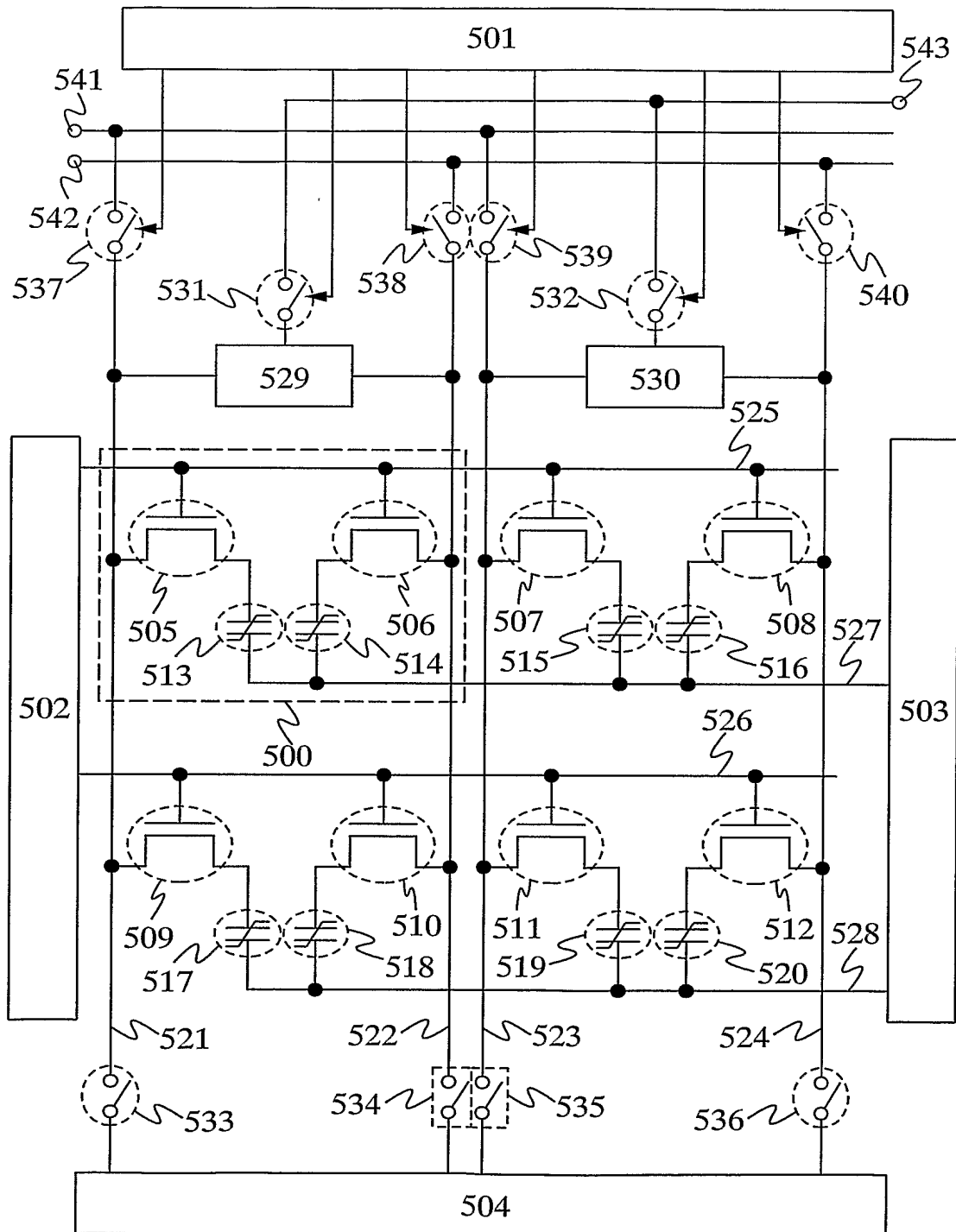
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FIG. 4



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FIG. 5



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FIG. 6

top electrode layer (Ir/IrO <sub>2</sub> or the like)
ferroelectric layer (PZT or the like)
bottom electrode layer (Pt/IrO <sub>2</sub> or the like)

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FIG. 7

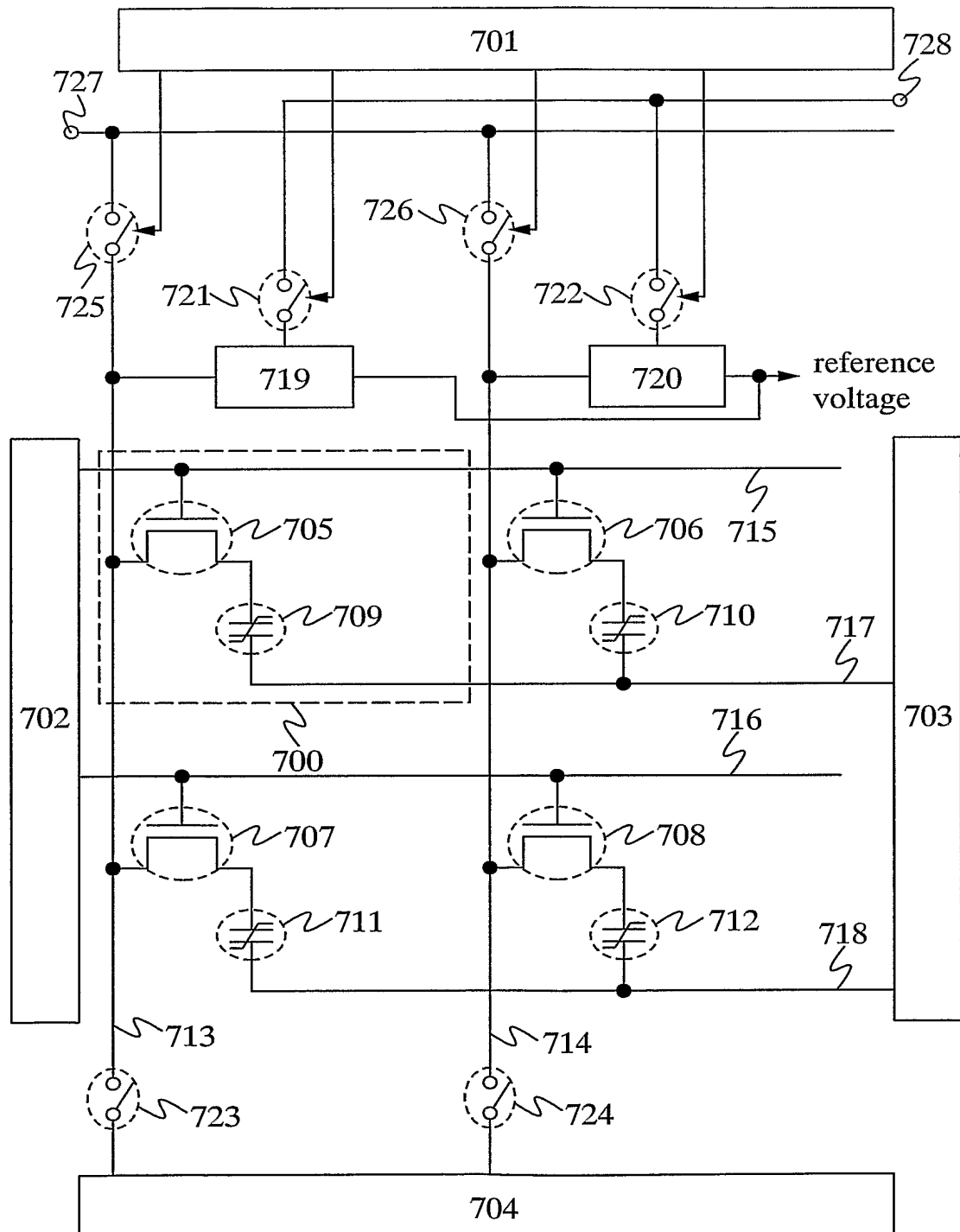


FIG. 8

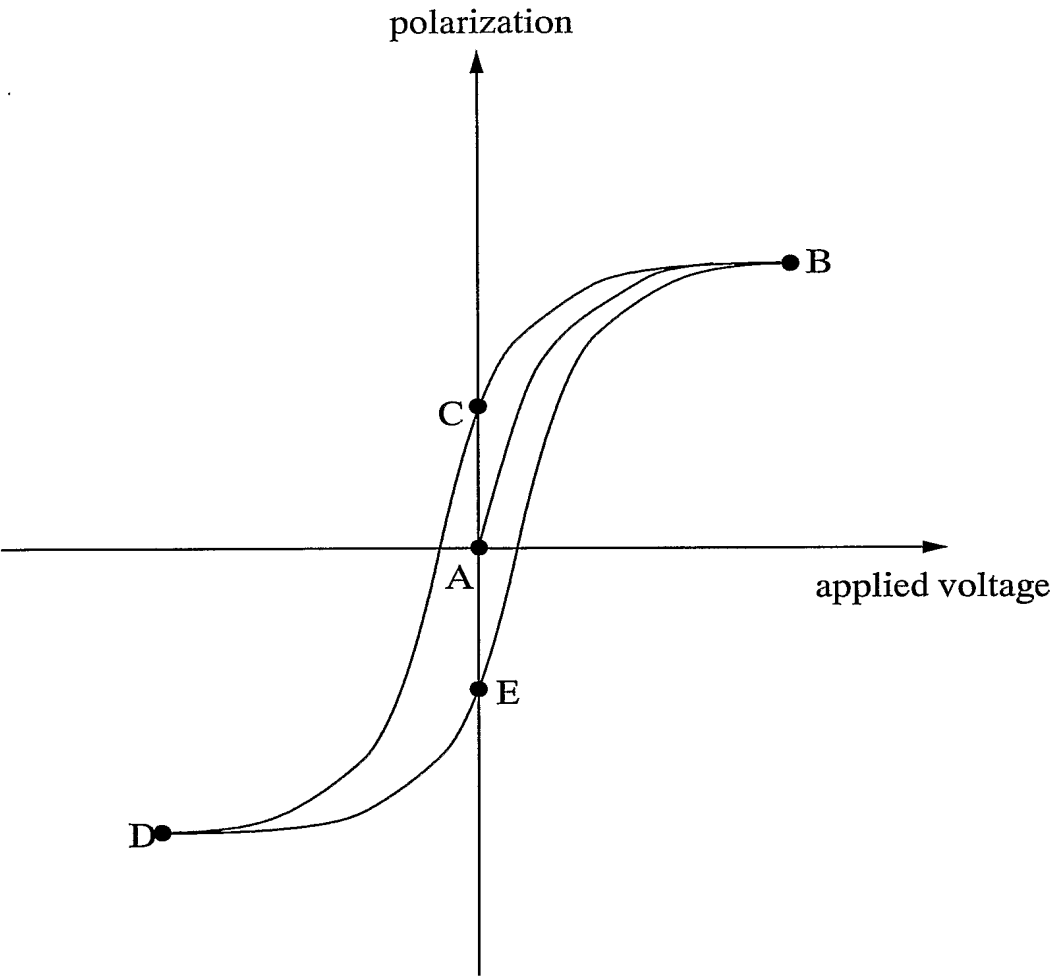
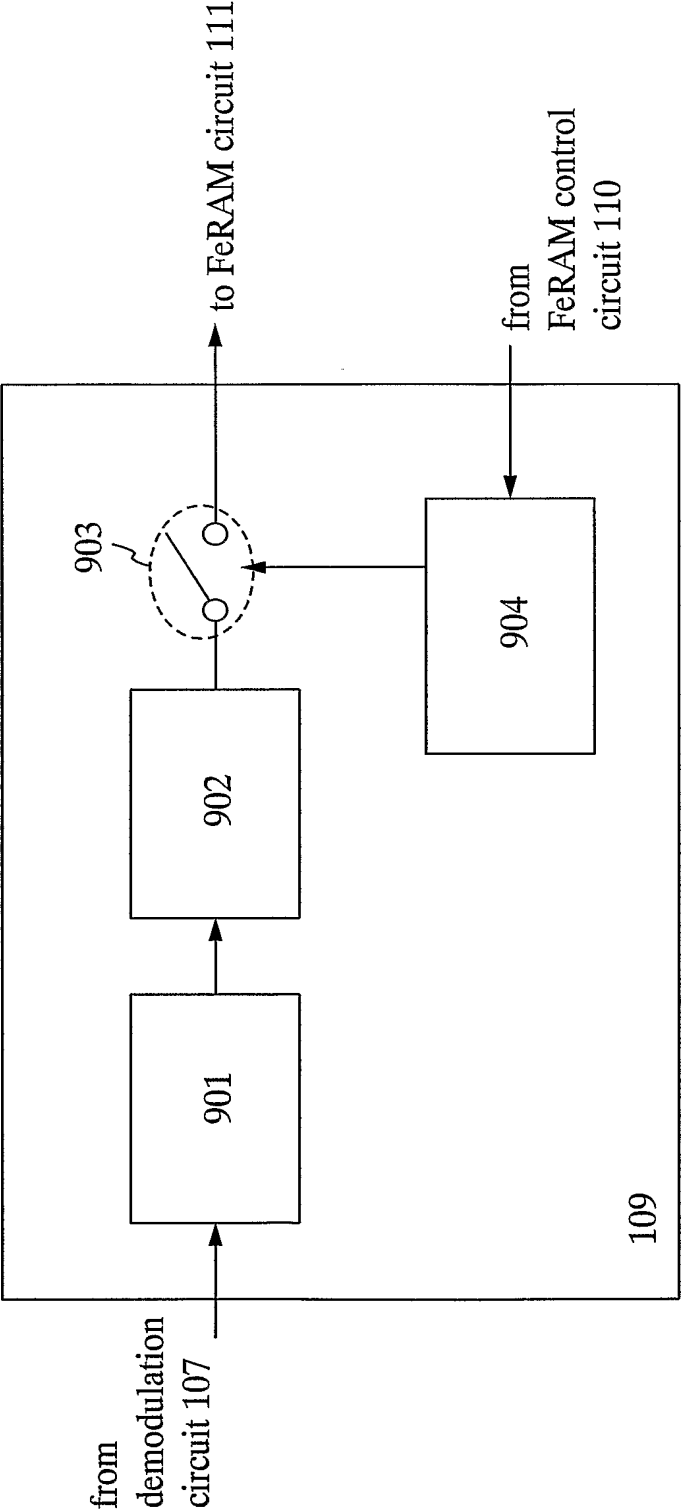




FIG. 9



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FIG. 10A

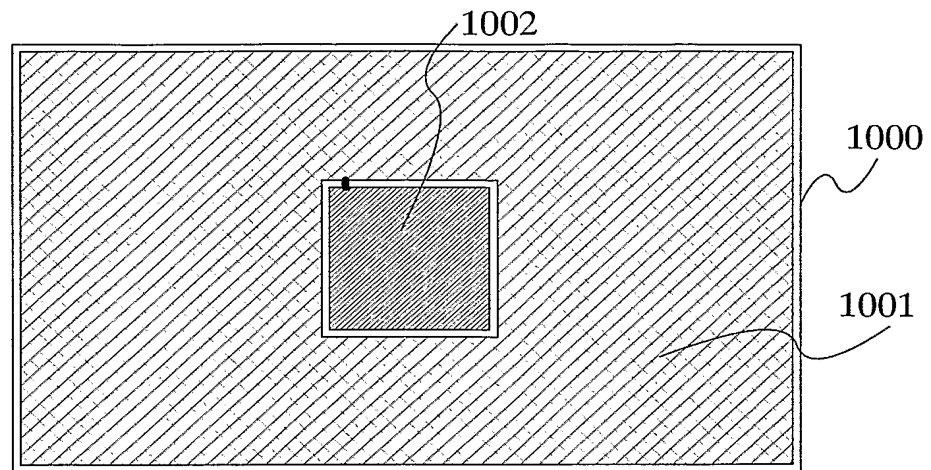


FIG. 10B

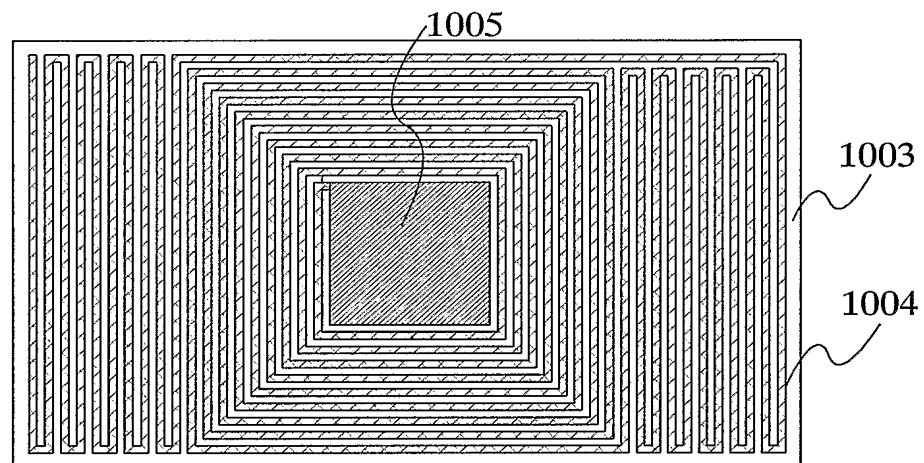


FIG. 10C

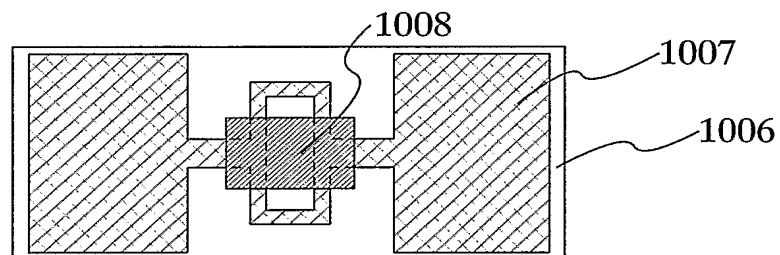


FIG. 10D

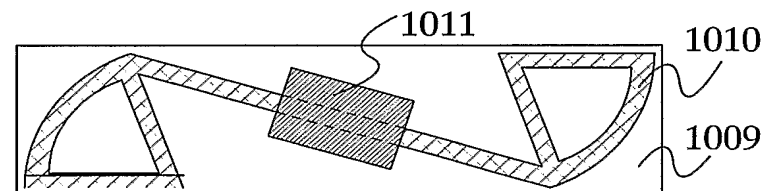
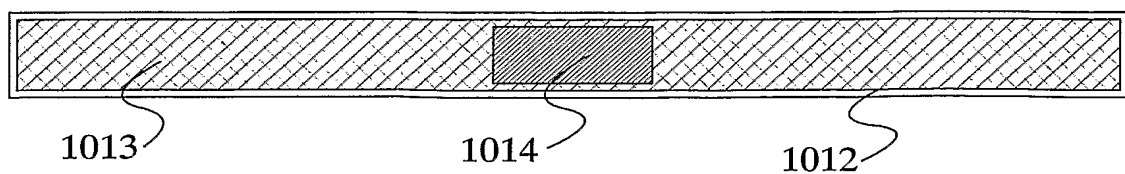


FIG. 10E



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FIG. 11A

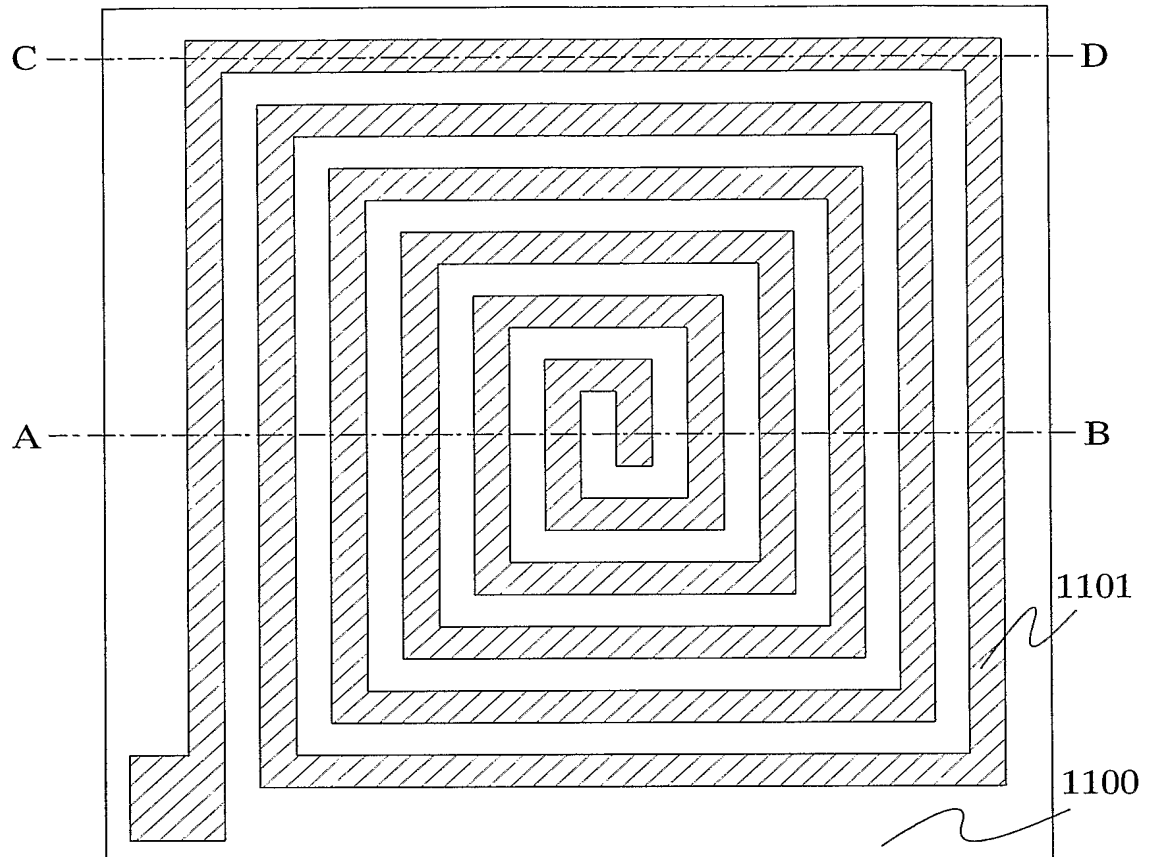


FIG. 11B

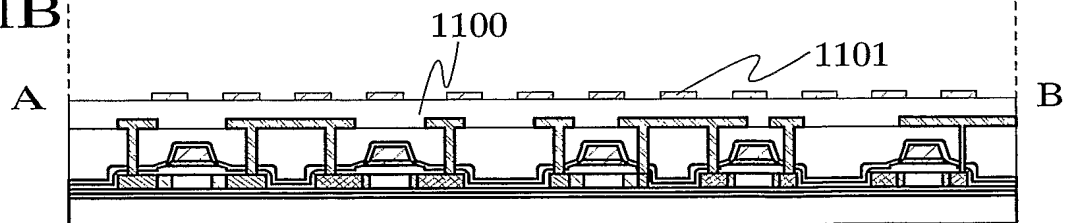


FIG. 11C

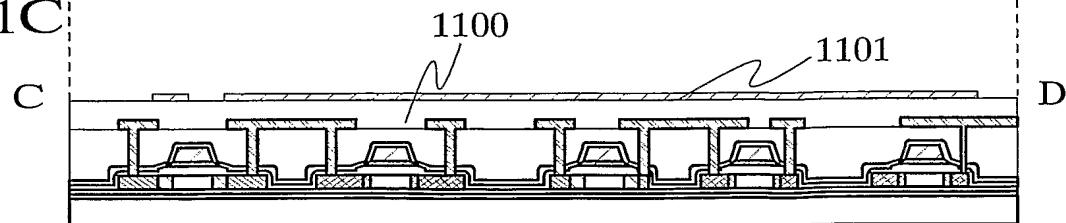


FIG. 12A

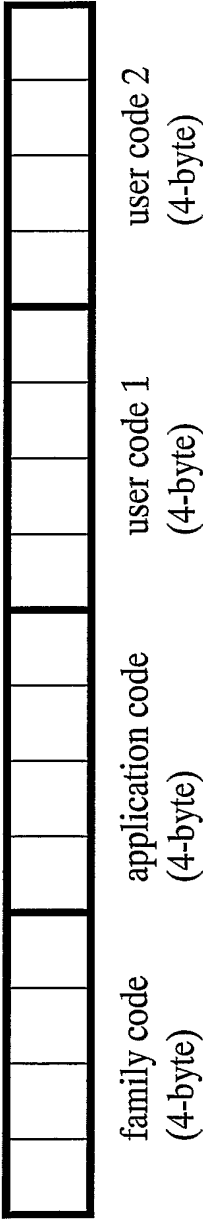


FIG. 12B

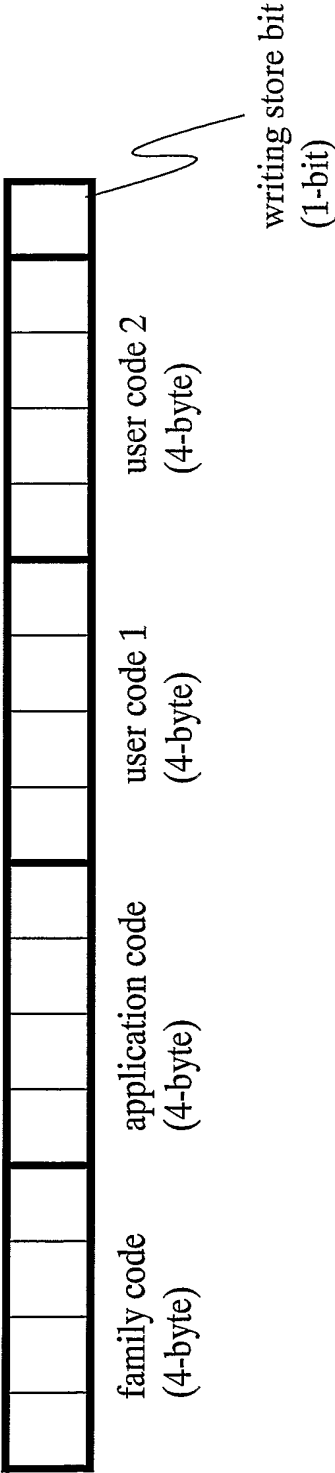


FIG. 13

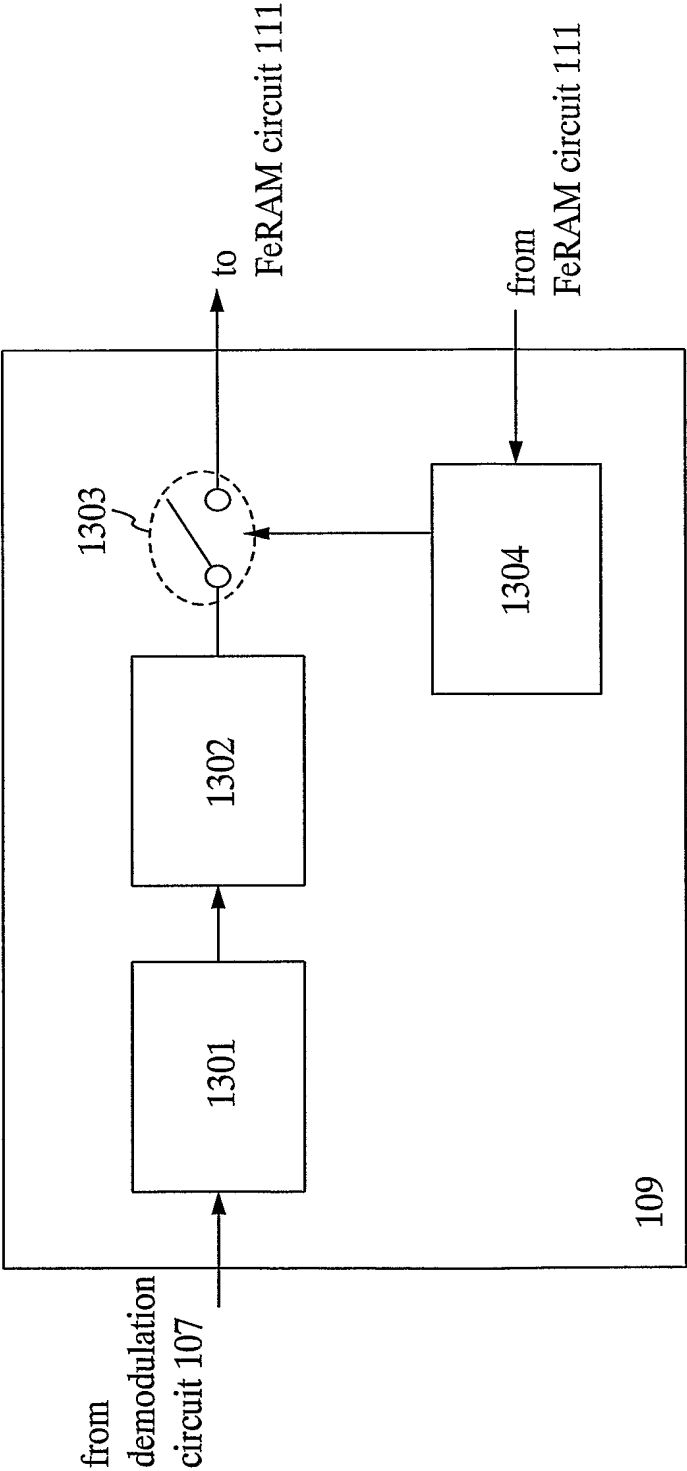


FIG. 14A

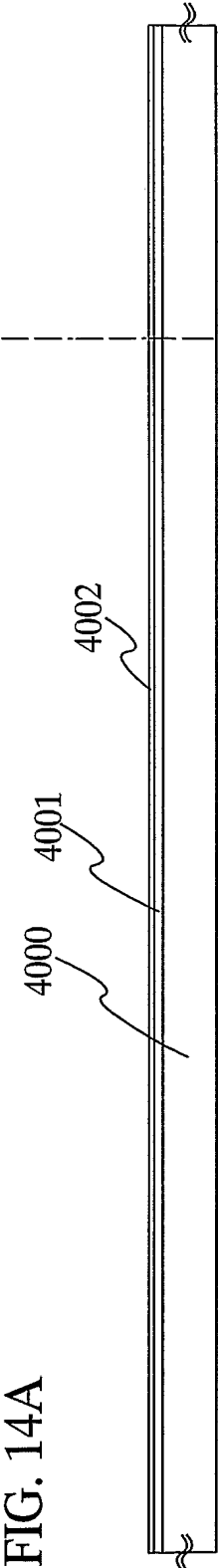


FIG. 14B

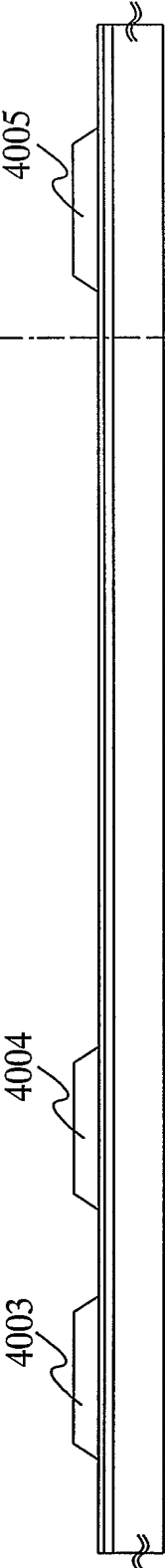
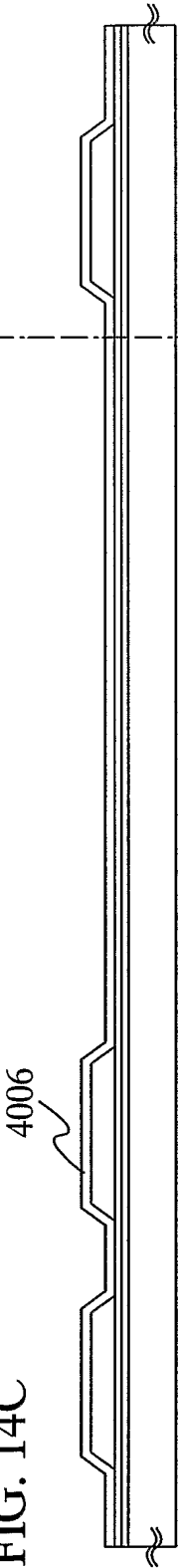


FIG. 14C



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FIG. 15A

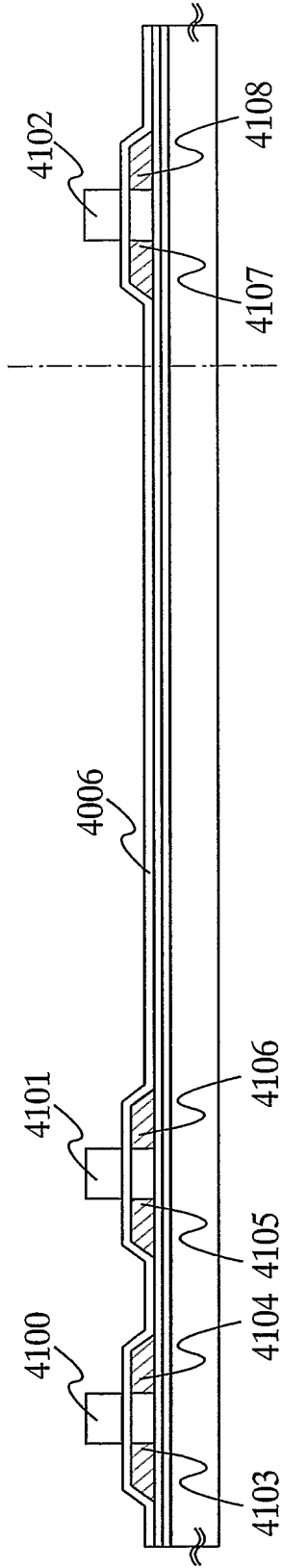


FIG. 15B

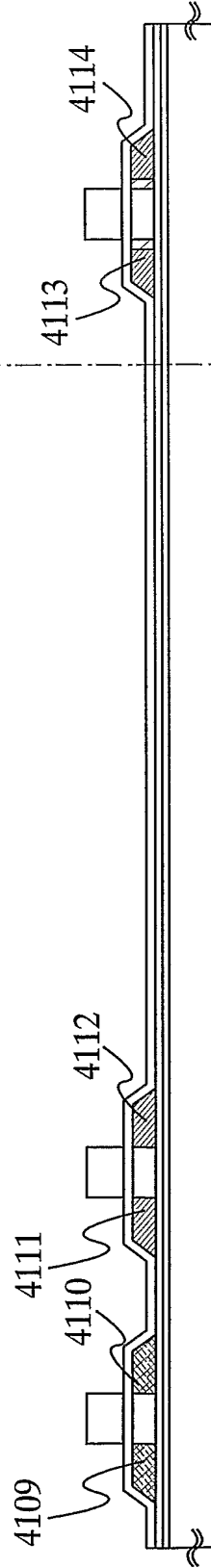
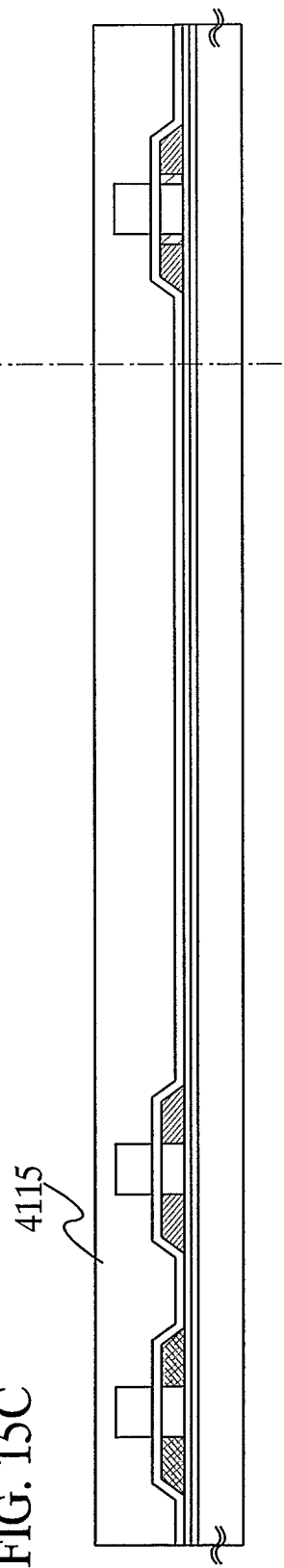


FIG. 15C



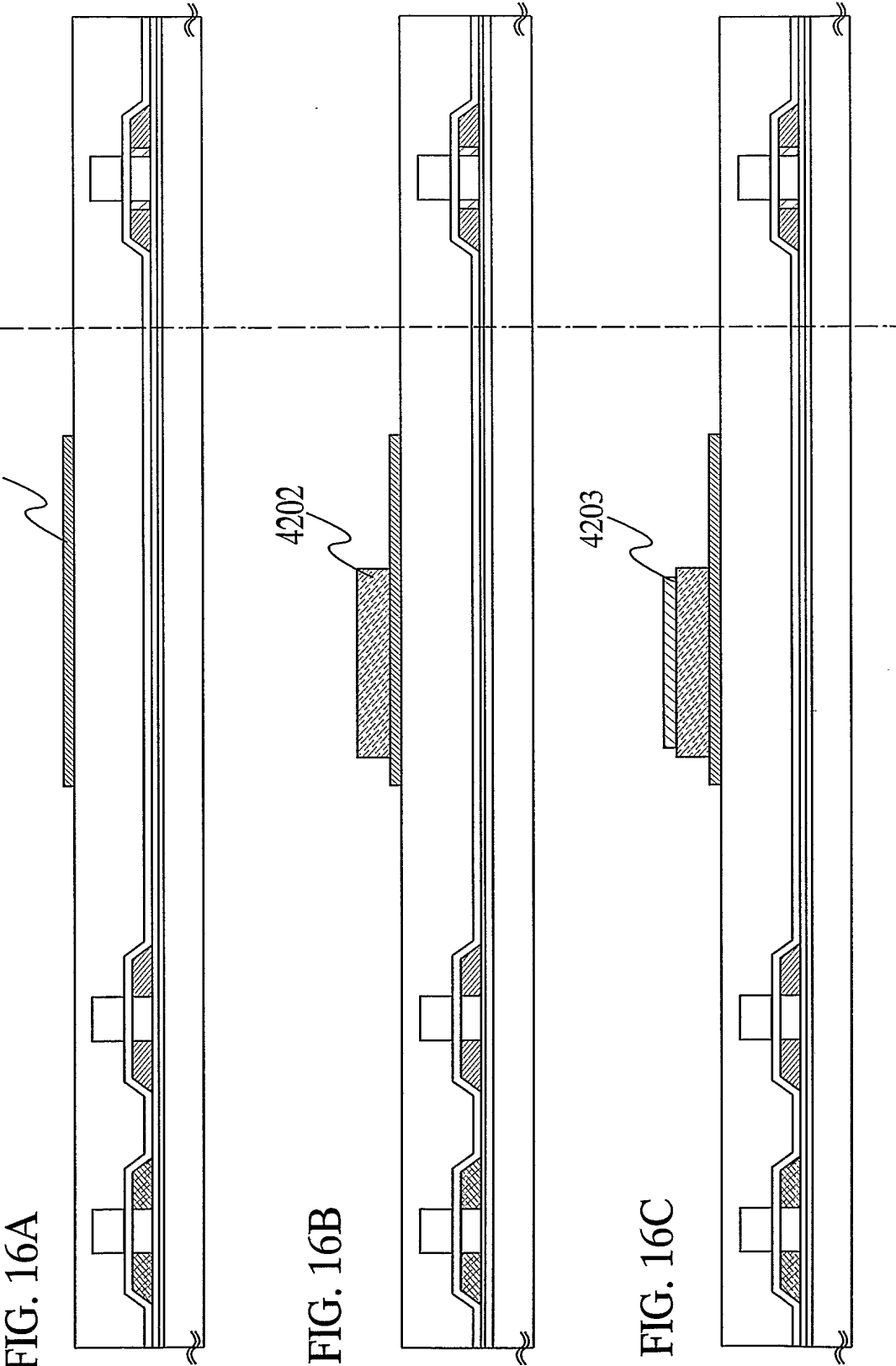




FIG. 17A

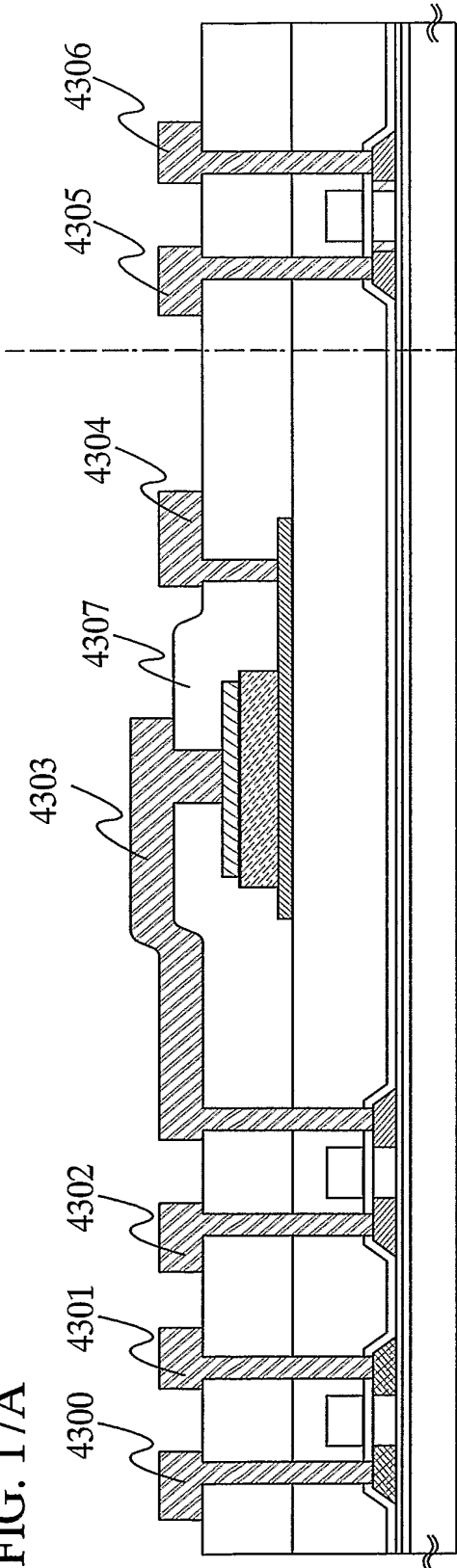
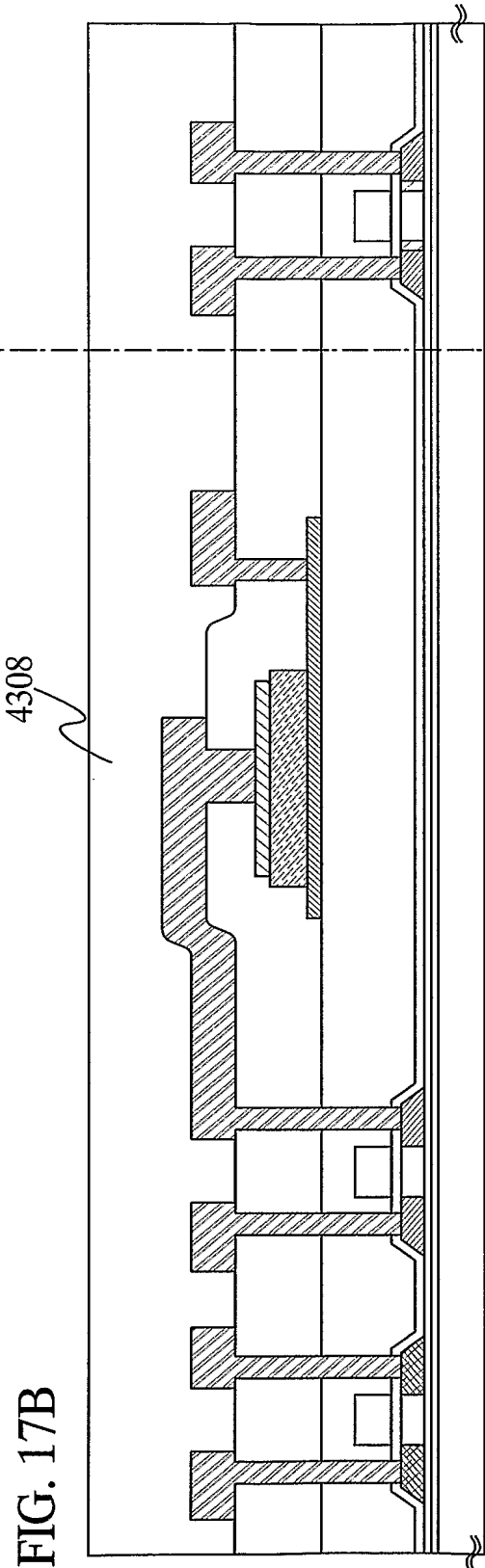


FIG. 17B



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FIG. 18A

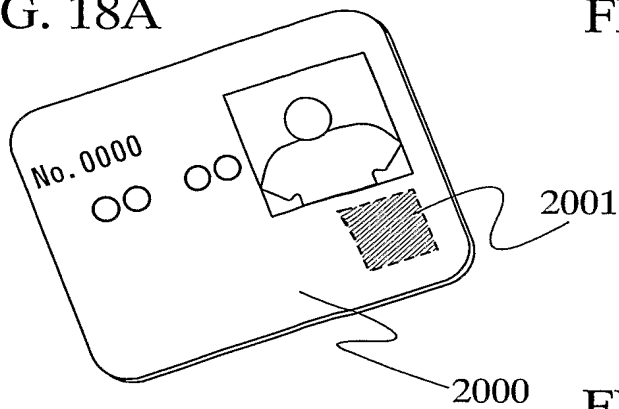


FIG. 18B

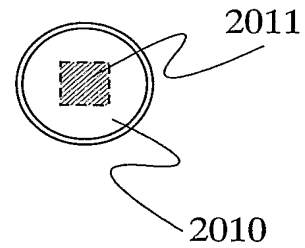


FIG. 18C

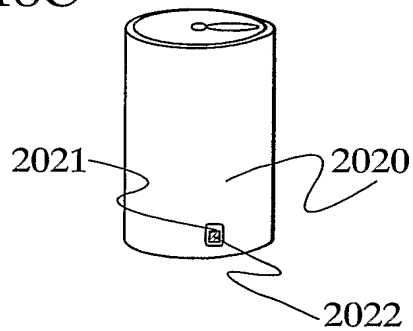


FIG. 18D

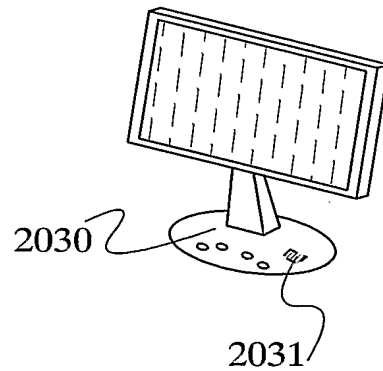


FIG. 18E

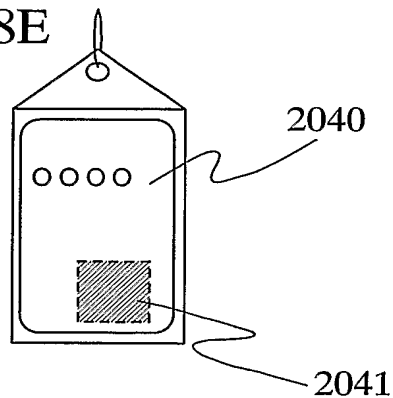


FIG. 18F

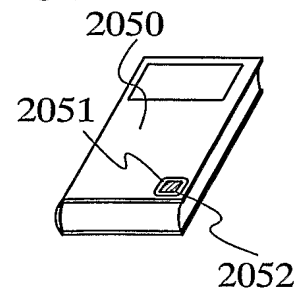


FIG. 18G

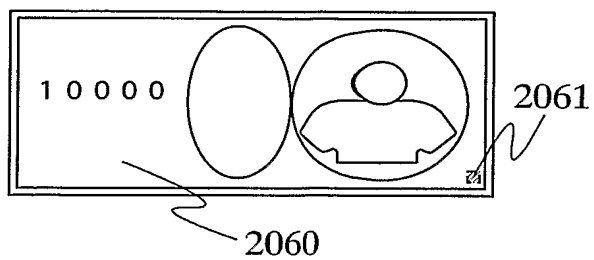
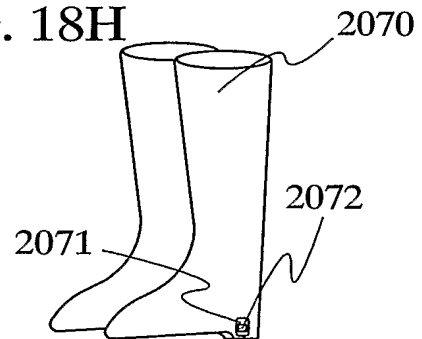
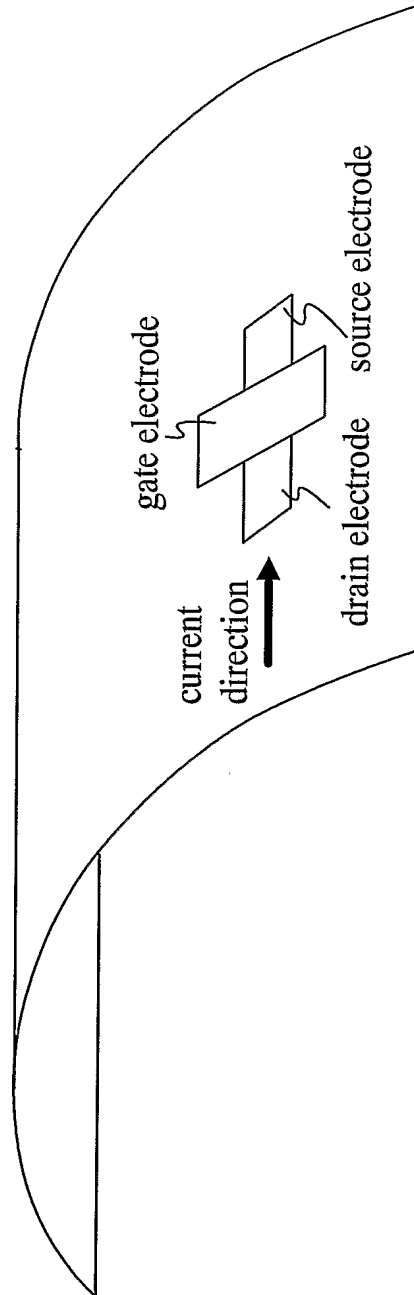


FIG. 18H



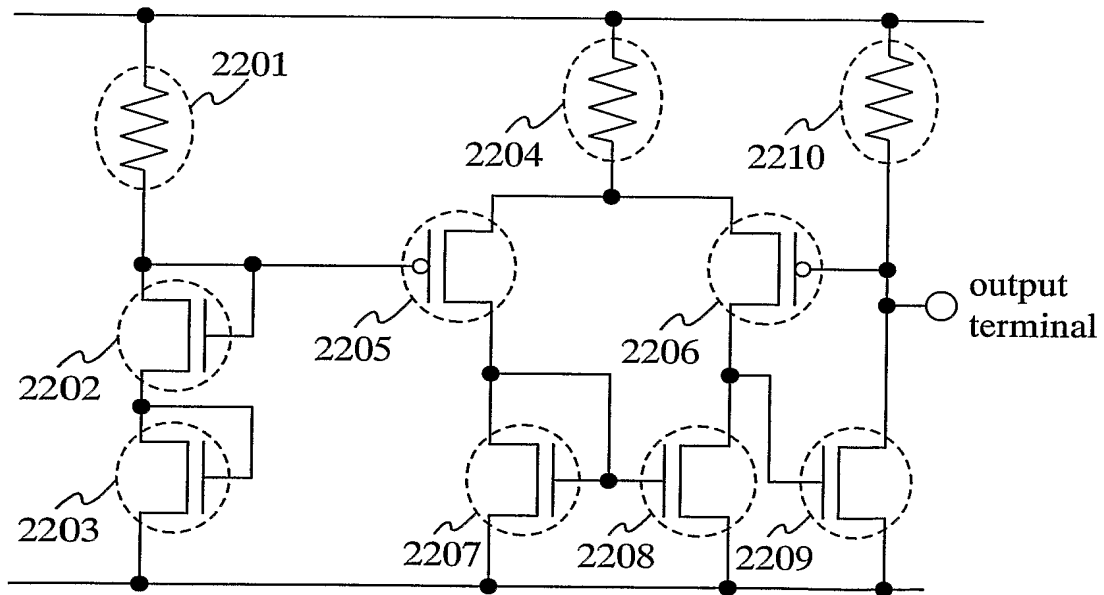
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FIG. 19



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FIG. 20



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FIG. 21A

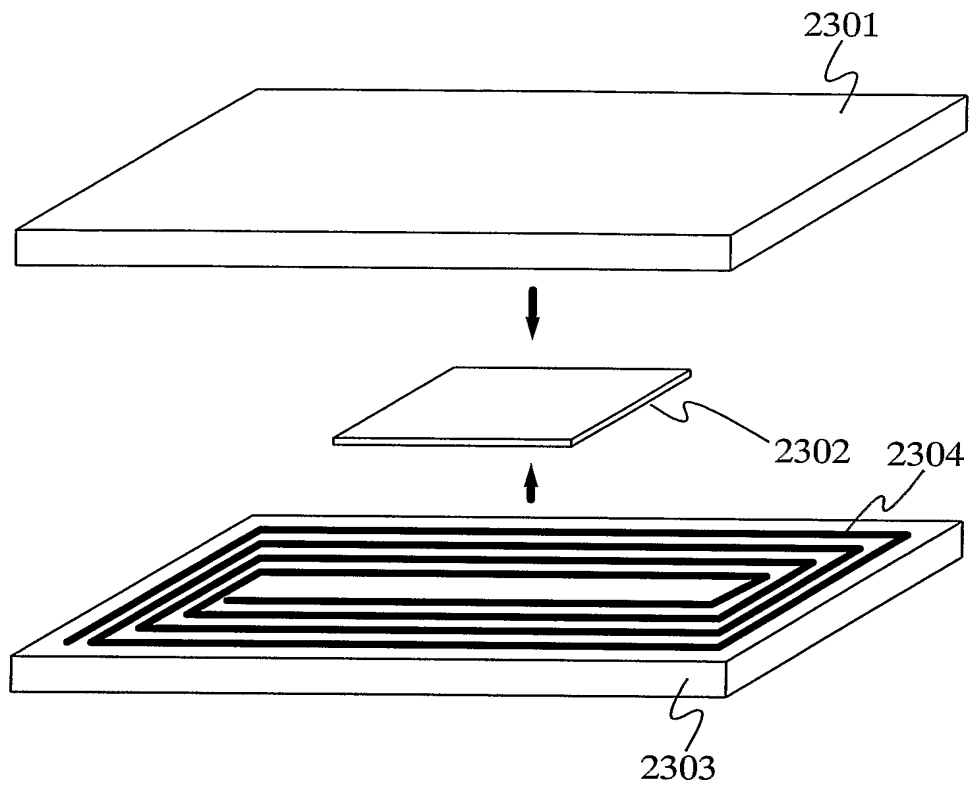
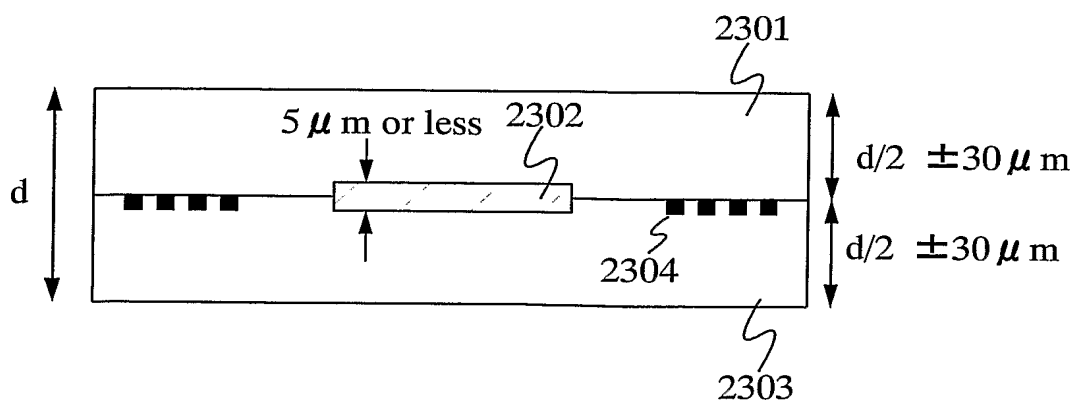


FIG. 21B



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FIG. 22A

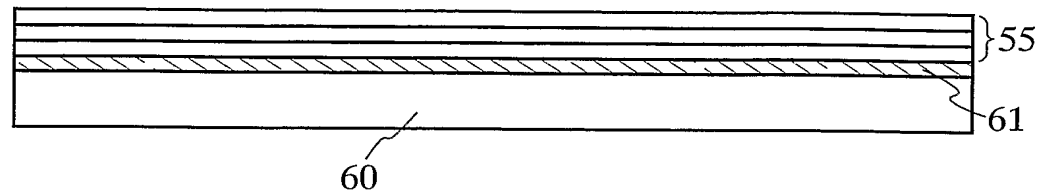


FIG. 22B

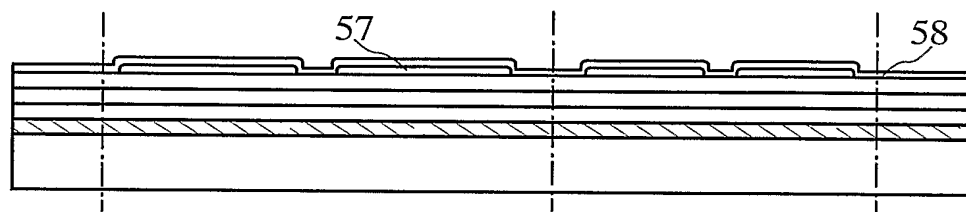


FIG. 22C

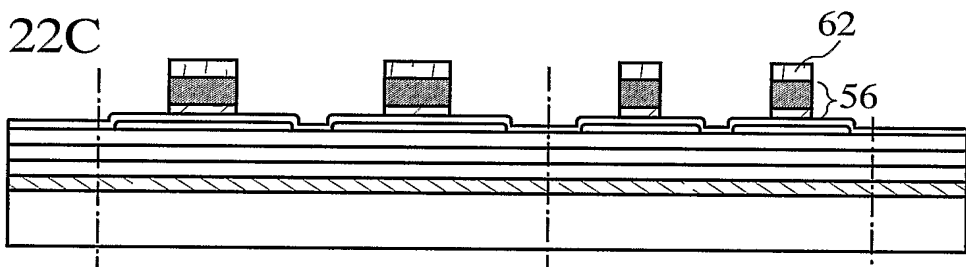


FIG. 22D

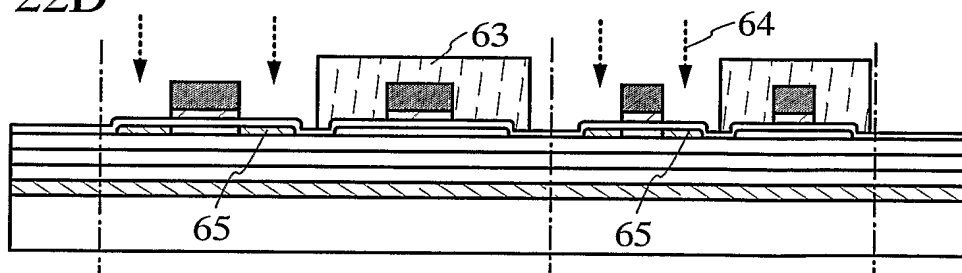
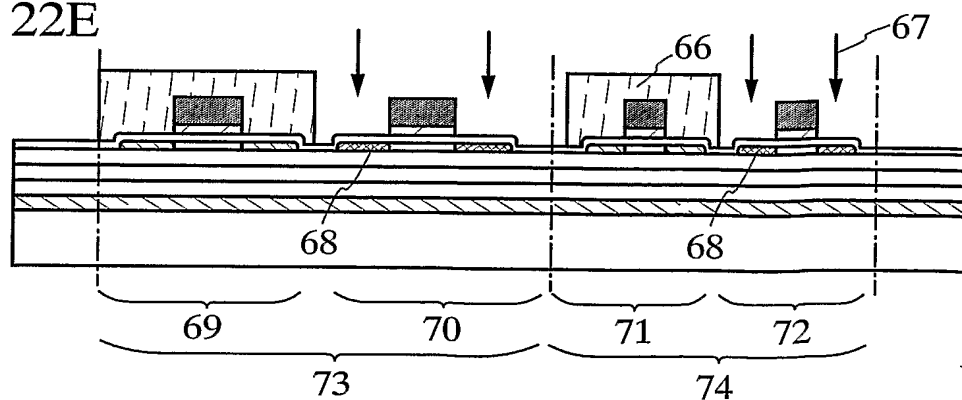


FIG. 22E



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FIG. 23A

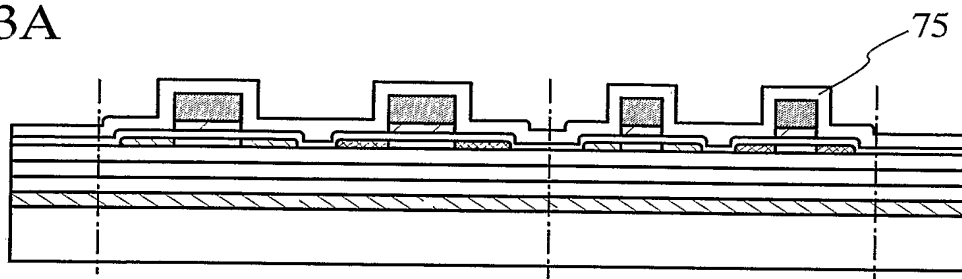


FIG. 23B

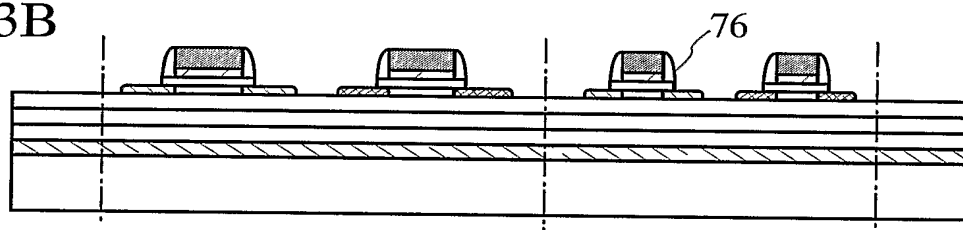


FIG. 23C

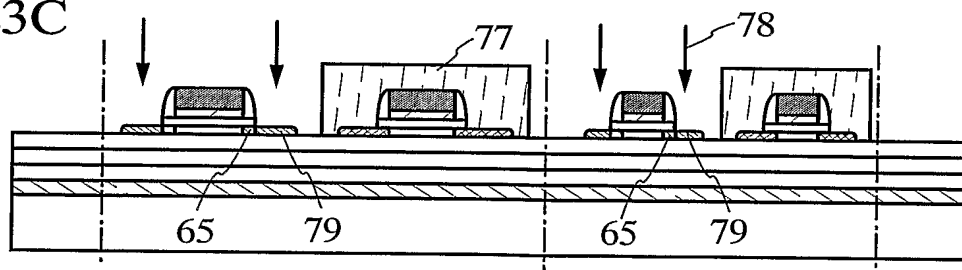
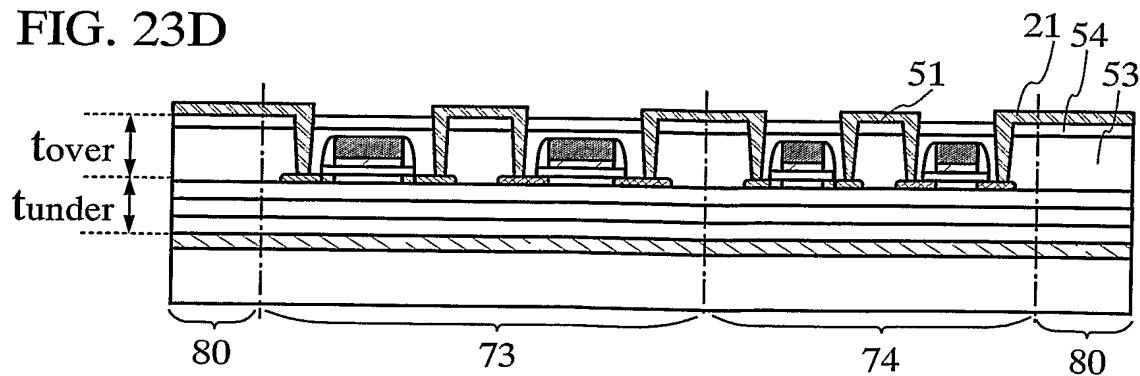


FIG. 23D



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FIG. 24A

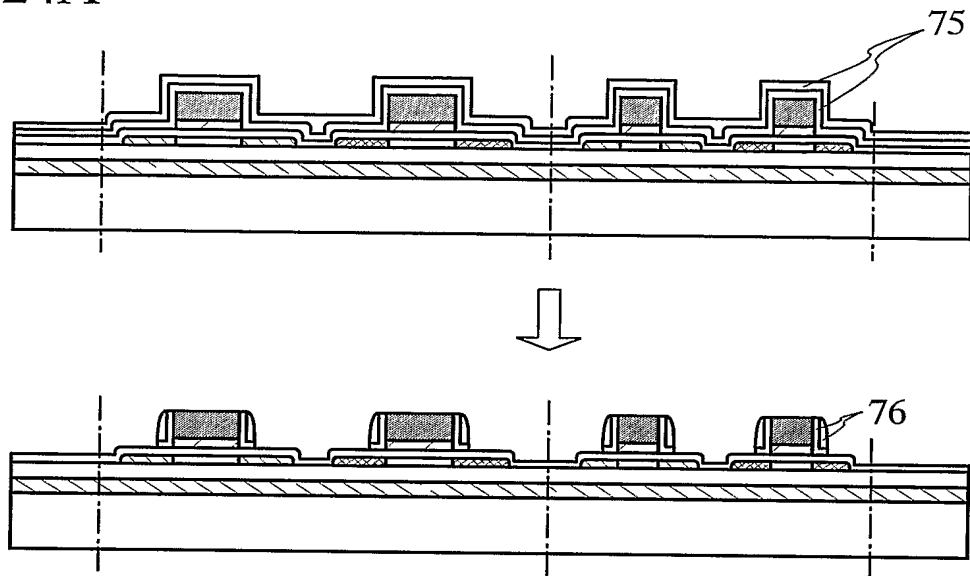
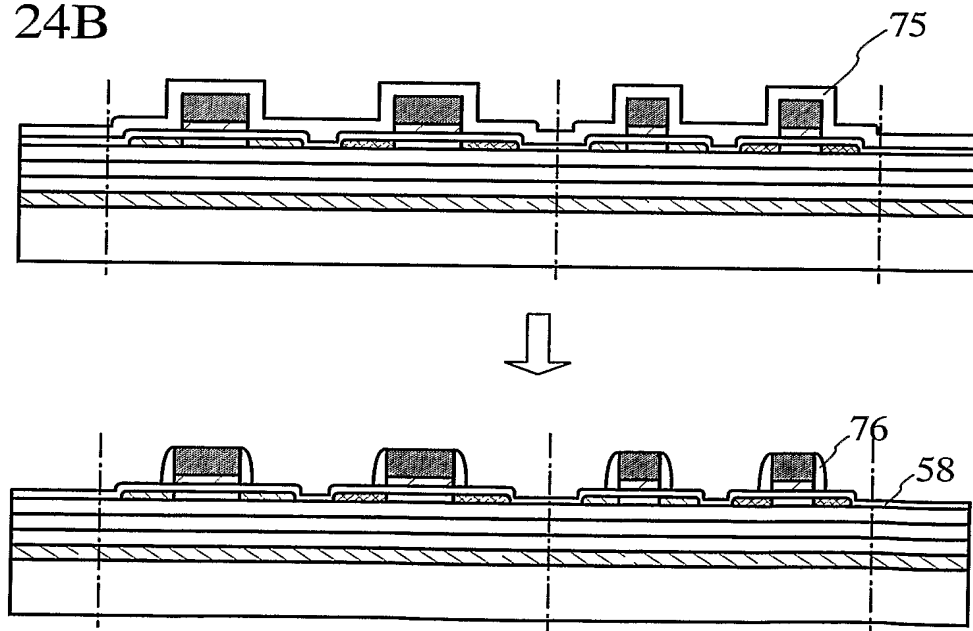


FIG. 24B





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FIG. 25

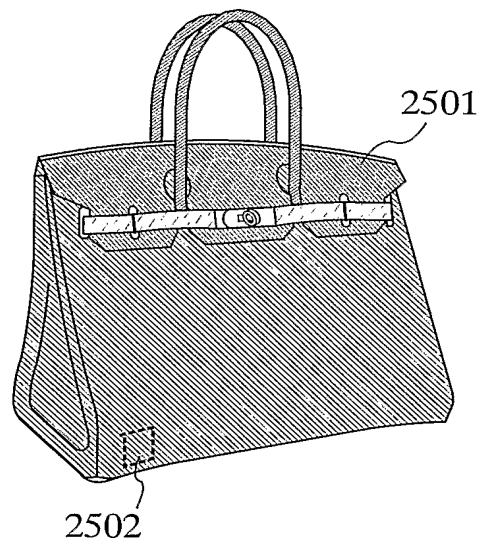


FIG. 26A

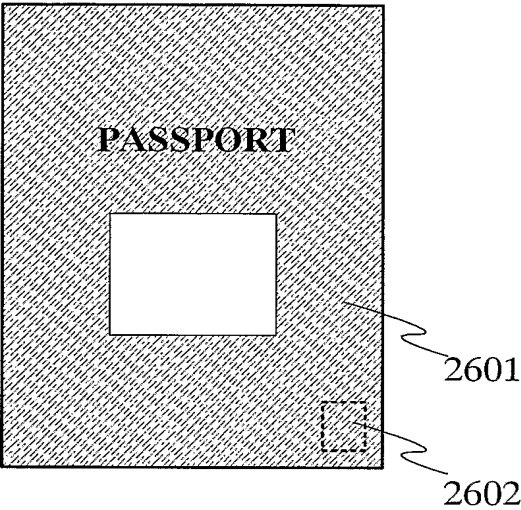


FIG. 26B

Name    ○○    ○○                      YYYY/MM/DD

Birth    ○○○○○○

Address    ○○○○○○

YYYY/MM/DD

Number    ○○○○○○

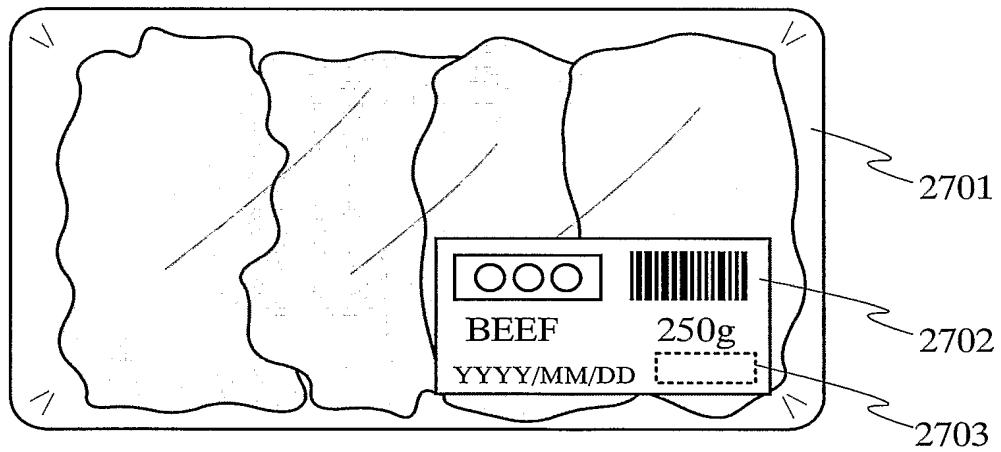
Others    \_\_\_\_\_

2603

2604

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FIG. 27



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FIG. 28A

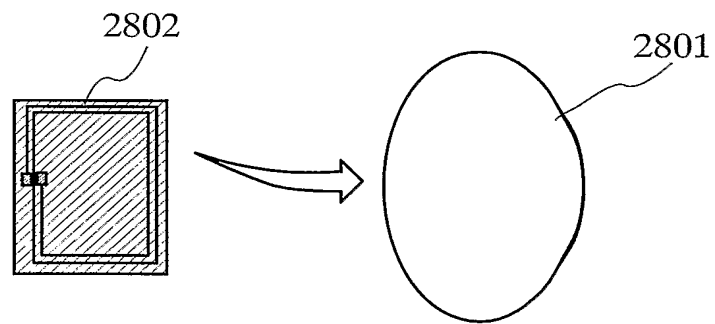
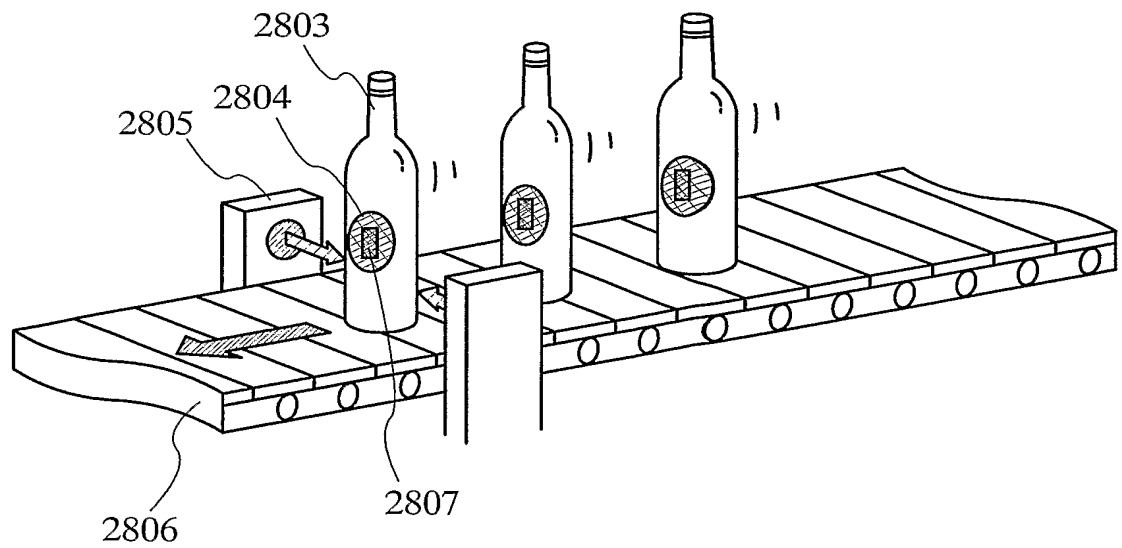
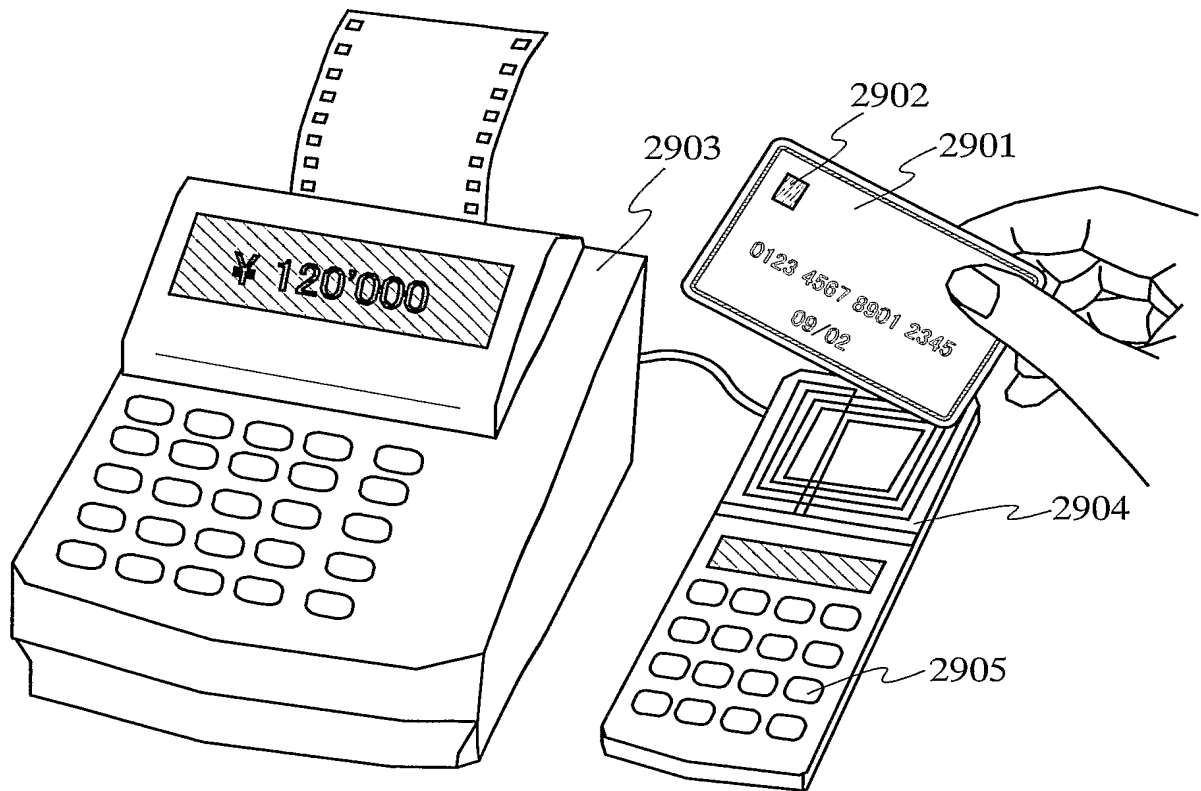


FIG. 28B



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FIG. 29



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## EXPLANATION OF REFERENCE

5 21...connecting wiring, 51...wiring, 53...interlayer film, 54...protective film,  
 55...protective film, 56...gate electrode, 57...island-shaped semiconductor film,  
 58...gate insulating film, 60...substrate, 61...peeling layer, 62...resist, 63...resist,  
 64...impurity element, 65...low concentration impurity region, 66...resist,  
 67...impurity element, 68...high concentration impurity region, 69...N-channel TFT,  
 10 70...P-channel TFT, 71...N-channel TFT, 72...P-channel TFT, 73...CPU, 74...memory,  
 75...insulating film, 76...sidewall, 77...resist, 78...impurity element, 79...high  
 concentration impurity region, 80...terminal portion, 100...semiconductor device,  
 101...antenna circuit, 102...rectifying circuit, 103...stabilizing power source circuit,  
 104...modulation circuit, 105...amplifier, 106...logic circuit, 107...demodulation  
 15 circuit, 108...amplifier, 109...logic circuit, 110...FeRAM control circuit, 111...FeRAM  
 circuit, 200...semiconductor device, 201...antenna circuit, 202...rectifying circuit,  
 203...stabilizing power source circuit, 204...modulation circuit, 205...amplifier,  
 206...logic circuit, 207...demodulation circuit, 208...amplifier, 209...logic circuit,  
 210...memory control circuit, 211...memory circuit, 301...antenna coil, 302...tuning  
 20 capacitor, 303 and 304...diodes, 305...smoothing capacitor, 401...ID chip,  
 402...antenna unit, 403...interrogator, 404...bag, 500...memory cell, 501...bit line  
 decoder, 502...word line decoder, 503...plate line decoder, 504...precharge circuit, 505  
 to 512...N-channel memory transistors (transistors), 513 to 520...ferroelectric  
 capacitors, 521 to 524...bit lines, 525 and 526...word lines, 527 and 528...plate lines,  
 25 529 and 530...sense amplifiers, 531 and 532...sense amplifier selecting switches, 533  
 to 536...precharge switches, 537 to 540...bit line selecting switches, 541 and  
 542...input terminals, 543...output terminal, 700...memory cell, 701...bit line decoder,  
 702...word line decoder, 703...plate line decoder, 704...precharge circuit, 705 to  
 708...N-channel memory transistors (transistors), 709 to 712...ferroelectric capacitors,  
 30 713 and 714...bit lines, 715 and 716...word lines, 717 and 718...plate lines, 719 and

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720...sense amplifiers, 721 and 722...sense amplifier selecting switches, 723 and  
5 724...precharge switches, 725 and 726...bit line selecting switches, 727...input  
terminal, 728...output terminal, 901...decode circuit, 902...delay circuit, 903...switch,  
904...1-bit FeRAM circuit, 1000...substrate, 1001...antenna, 1002...circuit,  
1003...substrate, 1004...antenna, 1005...circuit, 1006...substrate, 1007...antenna,  
1008...circuit, 1009...substrate, 1010...antenna, 1011...circuit, 1012...substrate,  
10 1013...antenna, 1014...circuit, 1100...substrate (top substrate), 1101...antenna  
(antenna wiring), 1301...decode circuit, 1302...delay circuit, 1303...switch,  
1304...volatile memory circuit, 2000...IC card, 2001...circuit portion, 2010...ID tag,  
2011...circuit portion, 2020...product, 2021...protective film, 2022...ID chip,  
2030...housing, 2031...ID chip, 2040...shipping tag, 2041...ID chip, 2050...book,  
15 2051...protective film, 2052...ID chip, 2060...bill, 2061...ID chip, 2070...shoe,  
2071...protective film, 2072...ID chip, 2201...resistor, 2202...transistor,  
2203...transistor, 2204...current supply resistor, 2205 to 2209...transistors,  
2210...resistor, 2301...flexible protective layer (protective layer), 2302...ID chip,  
2303...flexible protective layer (protective layer), 2304...antenna, 2501...bag,  
20 2502...ID chip, 2601...passport, 2602...ID chip, 2603...driver's license 2604...ID chip,  
2701...package, 2702...display label, 2703...ID chip, 2801...label, 2802...ID chip,  
2803...beer bottle, 2804...label, 2805...writer device, 2806...conveyor belt, 2807...ID  
chip, 2901...IC card, 2902...ID chip, 2903...register, 2904...reader/writer, 2905...key,  
4000...substrate, 4001 and 4002...base films, 4003 to 4005...island-shaped  
25 semiconductor layers, 4006...gate insulating film, 4100 to 4102...gate electrodes, 4103  
to 4108... low concentration P-type impurity regions, 4109 and 4100...high  
concentration N-type impurity regions, 4111 to 4114...high concentration N-type  
impurity regions, 4115...interlayer insulating film, 4201...bottom electrode layer,  
4202...ferroelectric layer, 4203...top electrode layer, 4300 to 4306...wirings,  
30 4307...interlayer insulating film, 4308...protective film